

# MSKSEMI 美森科

SEMICONDUCTOR



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PLED

## P6SMBXXXA(CA)(MS)

### Product specification

**Features**

- For surface mounted applications in order to optimize board space
- Low profile package
- Built-in strain relief
- Glass passivated junction
- Low inductance
- Excellent clamping capability
- 600W peak pulse power capability at 10/1000μswaveform, repetition rate (duty cycle): 0.01%
- Fast response time
- Typical IR less than 1μA above 12V
- High Temperature soldering: 260°C/ 40 seconds at terminals
- Plastic package has underwriters laboratory flammability 94V-0


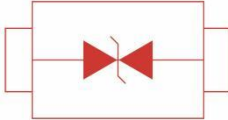


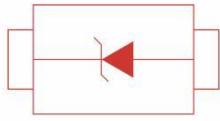
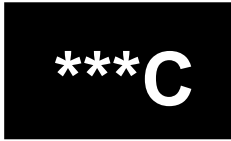
**Mechanical Data**

**Case :** JEDEC DO-214AA/SMB molded plastic body  
**Terminals :** Solderable per MIL-STD-750,Method 2026  
**Polarity :** Polarity symbol marking on body  
**Mounting Position :** Any  
**Weight :** 0.003 ounce, 0.095 grams

**Applications**

- I/O interface
- AC/DC power supply
- Industrial and Consumer electronic applications.

**Reference News**

PACKAGE OUTLINE	PIN CONFIGURATION	Marking Information
		
<b>Unipolar</b>		
		
<b>Bipolar</b>		

## Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation at $T_A=25^\circ\text{C}$ by 10x1000 $\mu\text{s}$ waveform (Fig.1) (Note 1), (Note 2)	$P_{PPM}$	600	Watts
Power Dissipation on infinite heat sink at $T_A=50^\circ\text{C}$	$P_{M(AV)}$	5.0	Watts
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	$I_{FSM}$	100	Amps
Maximum Instantaneous Forward Voltage at 50A for Unidirectional only (Note 4)	$V_F$	3.5V/5.0	V
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-65 to +150	°C
Typical Thermal Resistance Junction to Lead	$R_{\theta JL}$	20	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	100	°C/W

### NOTES:

1. Non-repetitive current pulse, per Fig. 3 and derated above  $T_A = 25^\circ\text{C}$  per Fig. 2.
2. Mounted on copper pad area of 0.2x0.2" (5.0 x 5.0mm) to each terminal.
3. Measured on 8.3ms single half sine wave or equivalent square wave for unidirectional device only, duty cycle=4 per minute maximum.
4.  $V_F < 3.5\text{V}$  for  $V_{BR} < 200\text{V}$  and  $V_F < 5.0\text{V}$  for  $V_{BR} > 201\text{V}$ .

## Electrical Characteristics (TA=25°C)

Part Number		Device Marking Code		Reverse Stand-Off Voltage	Breakdown Voltage @ $I_T$	Test Current	Maximum Clamping Voltage @ $I_{PP}$	Peak Pulse Current	Reverse Leakage @ $V_{RWM}$
Unidirectional	Bidirectional	UNI	BI	$V_{RWM}(V)$	$V_{BR}(V)$	$I_T(mA)$	$V_C(V)$	$I_{PP}(A)$	$I_R(\mu A)$
P6SMB6.8A (MS)	P6SMB6.8CA (MS)	6V8A	6V8C	5.80	6.45~7.14	10	10.5	58.1	1000
P6SMB7.5A (MS)	P6SMB7.5CA (MS)	7V5A	7V5C	6.40	7.13~7.88	10	11.3	54.0	500
P6SMB8.2A (MS)	P6SMB8.2CA (MS)	8V2A	8V2C	7.02	7.79~8.61	10	12.1	50.4	200
P6SMB9.1A (MS)	P6SMB9.1CA (MS)	9V1A	9V1C	7.78	8.65~9.55	1	13.4	45.5	50
P6SMB10A (MS)	P6SMB10CA (MS)	10A	10C	8.55	9.50~10.50	1	14.5	42.1	10
P6SMB11A (MS)	P6SMB11CA (MS)	11A	11C	9.40	10.50~11.60	1	15.6	39.1	5
P6SMB12A (MS)	P6SMB12CA (MS)	12A	12C	10.20	11.40~12.60	1	16.7	36.5	5
P6SMB13A (MS)	P6SMB13CA (MS)	13A	13C	11.10	12.40~13.70	1	18.2	33.5	1
P6SMB15A (MS)	P6SMB15CA (MS)	15A	15C	12.80	14.30~15.80	1	21.2	28.8	1
P6SMB16A (MS)	P6SMB16CA (MS)	16A	16C	13.60	15.20~16.80	1	22.5	27.1	1
P6SMB18A (MS)	P6SMB18CA (MS)	18A	18C	15.30	17.10~18.90	1	25.2	24.2	1
P6SMB20A (MS)	P6SMB20CA (MS)	20A	20C	17.10	19.00~21.00	1	27.7	22.0	1
P6SMB22A (MS)	P6SMB22CA (MS)	22A	22C	18.80	20.90~23.10	1	30.6	19.9	1
P6SMB24A (MS)	P6SMB24CA (MS)	24A	24C	20.50	22.80~25.20	1	33.2	18.4	1
P6SMB27A (MS)	P6SMB27CA (MS)	27A	27C	23.10	25.70~28.40	1	37.5	16.3	1
P6SMB30A (MS)	P6SMB30CA (MS)	30A	30C	25.60	28.50~31.50	1	41.4	14.7	1
P6SMB33A (MS)	P6SMB33CA (MS)	33A	33C	28.20	31.40~34.70	1	45.7	13.3	1

**Electrical Characteristics (TA=25°C)**

Part Number		Device Marking Code		Reverse Stand-Off Voltage	Breakdown Voltage @I <sub>r</sub>	Test Current	Maximum Clamping Voltage @I <sub>PP</sub>	Peak Pulse Current	Reverse Leakage @V <sub>RWM</sub>
Unidirectional	Bidirectional	UNI	BI	V <sub>RWM</sub> (V)	V <sub>BR</sub> (V)	I <sub>r</sub> (mA)	V <sub>C</sub> (V)	I <sub>PP</sub> (A)	k(μA)
P6SMB36A (MS)	P6SMB36CA (MS)	36A	36C	30.80	34.20~37.80	1	49.9	12.2	1
P6SMB39A (MS)	P6SMB39CA (MS)	39A	39C	33.30	37.10~41.00	1	53.9	11.3	1
P6SMB43A (MS)	P6SMB43CA (MS)	43A	43C	36.80	40.90~45.20	1	59.3	10.3	1
P6SMB47A (MS)	P6SMB47CA (MS)	47A	47C	40.20	44.70~49.40	1	64.8	9.4	1
P6SMB51A (MS)	P6SMB51CA (MS)	51A	51C	43.60	48.50~53.60	1	70.1	8.7	1
P6SMB56A (MS)	P6SMB56CA (MS)	56A	56C	47.80	53.20~58.80	1	77.0	7.9	1
P6SMB62A (MS)	P6SMB62CA (MS)	62A	62C	53.00	58.90~65.10	1	85.0	7.2	1
P6SMB68A (MS)	P6SMB68CA (MS)	68A	68C	58.10	64.60~71.40	1	92.0	6.6	1
P6SMB75A (MS)	P6SMB75CA (MS)	75A	75C	64.10	71.30~78.80	1	103.0	5.9	1
P6SMB82A (MS)	P6SMB82CA (MS)	82A	82C	70.10	77.90~86.10	1	113.0	5.4	1
P6SMB91A (MS)	P6SMB91CA (MS)	91A	91C	77.80	86.50~95.50	1	125.0	4.9	1
P6SMB100A (MS)	P6SMB100CA (MS)	100A	100C	85.50	95.00~105.00	1	137.0	4.5	1
P6SMB110A (MS)	P6SMB110CA (MS)	110A	110C	94.00	105.00~116.00	1	152.0	4.0	1
P6SMB120A (MS)	P6SMB120CA (MS)	120A	120C	102.00	114.00~126.00	1	165.0	3.7	1
P6SMB130A (MS)	P6SMB130CA (MS)	130A	130C	111.00	124.00~137.00	1	179.0	3.4	1
P6SMB150A (MS)	P6SMB150CA (MS)	150A	150C	128.00	143.00~158.00	1	207.0	2.9	1
P6SMB160A (MS)	P6SMB160CA (MS)	160A	160C	136.00	152.00~168.00	1	219.0	2.8	1
P6SMB170A (MS)	P6SMB170CA (MS)	170A	170C	145.00	162.00~179.00	1	234.0	2.6	1
P6SMB180A (MS)	P6SMB180CA (MS)	180A	180C	154.00	171.00~189.00	1	246.0	2.5	1
P6SMB200A (MS)	P6SMB200CA (MS)	200A	200C	171.00	190.00~210.00	1	274.0	2.2	1
P6SMB220A (MS)	P6SMB220CA (MS)	220A	220C	185.00	209.00~231.00	1	328.0	1.9	1
P6SMB250A (MS)	P6SMB250CA (MS)	250A	250C	214.00	237.00~263.00	1	344.0	1.8	1
P6SMB300A (MS)	P6SMB300CA (MS)	300A	300C	256.00	285.00~315.00	1	414.0	1.5	1
P6SMB350A (MS)	P6SMB350CA (MS)	350A	350C	300.00	332.00~368.00	1	482.0	1.3	1
P6SMB400A (MS)	P6SMB400CA (MS)	400A	400C	342.00	380.00~420.00	1	548.0	1.1	1
P6SMB440A (MS)	P6SMB440CA (MS)	440A	440C	376.00	418.00~462.00	1	602.0	1.0	1
P6SMB480A (MS)	P6SMB480CA (MS)	480A	480C	408.00	456.00~504.00	1	658.0	0.9	1
P6SMB510A (MS)	P6SMB510CA (MS)	510A	510C	434.00	485.00~535.00	1	698.0	0.9	1
P6SMB530A (MS)	P6SMB530CA (MS)	530A	530C	450.00	503.50~556.50	1	725.0	0.8	1
P6SMB540A (MS)	P6SMB540CA (MS)	540A	540C	459.00	513.00~567.00	1	740.0	0.8	1
P6SMB550A (MS)	P6SMB550CA (MS)	550A	550C	467.00	522.50~577.50	1	760.0	0.8	1

 Notes: For bidirectional type having V<sub>RWM</sub> of 10V and less, the I<sub>R</sub> limit is double.

**Ratings and Characteristic Curves ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

Figure 1. Peak Pulse Power Rating Curve

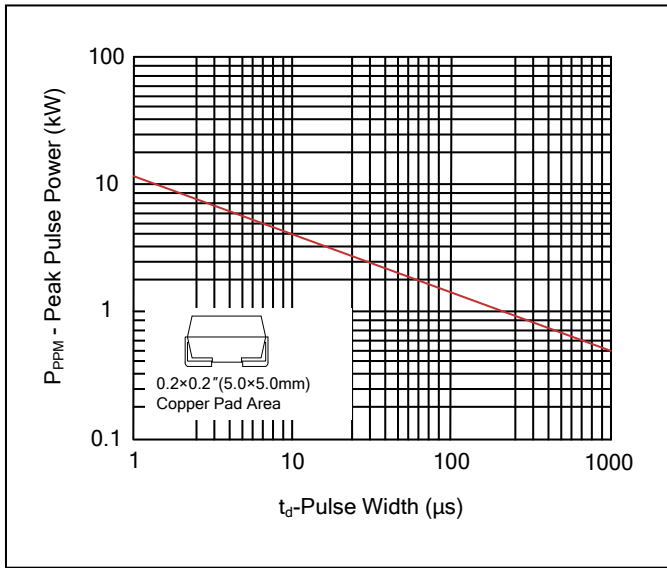


Figure 2. Pulse Derating Curve

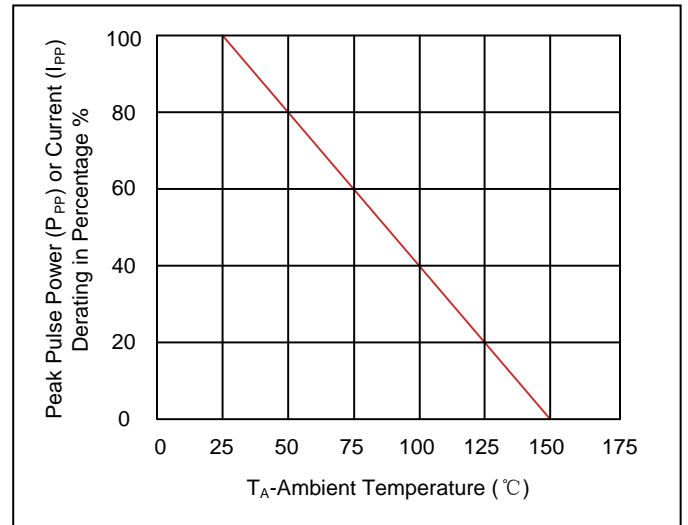


Figure 3. Pulse Waveform

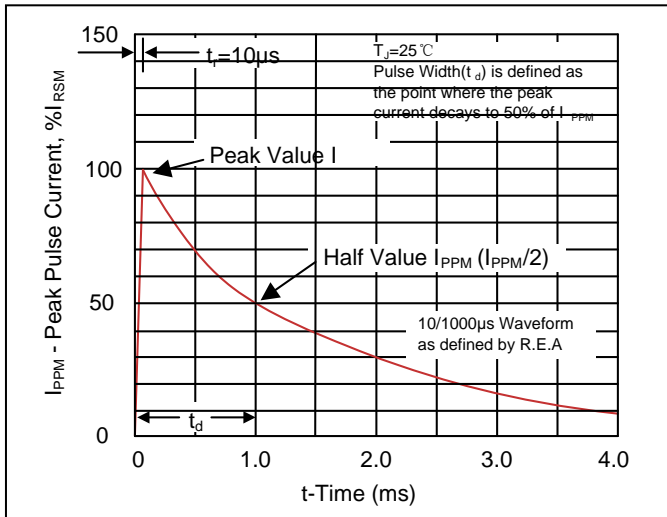


Figure 4. Typical Junction Capacitance

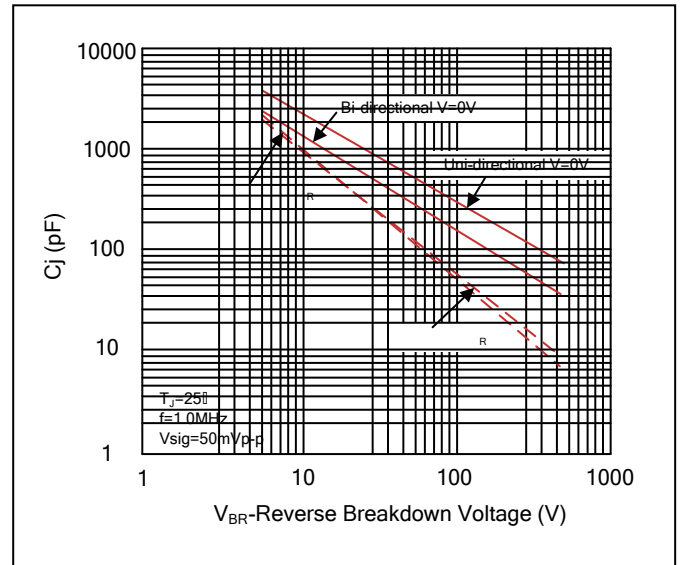


Figure 5. Steady State Power Dissipation Derating Curve

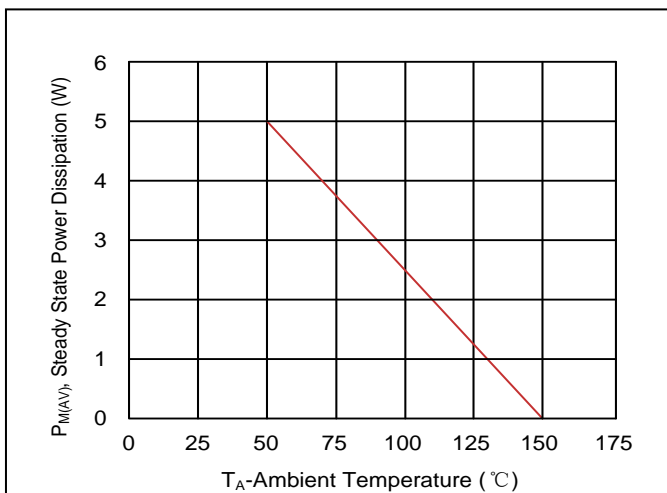
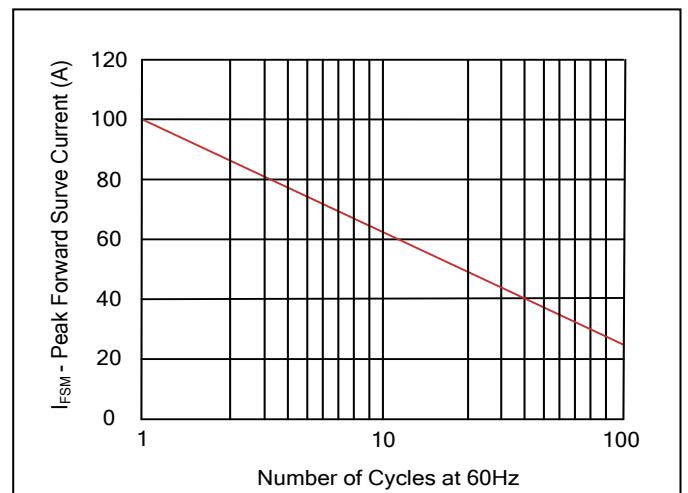
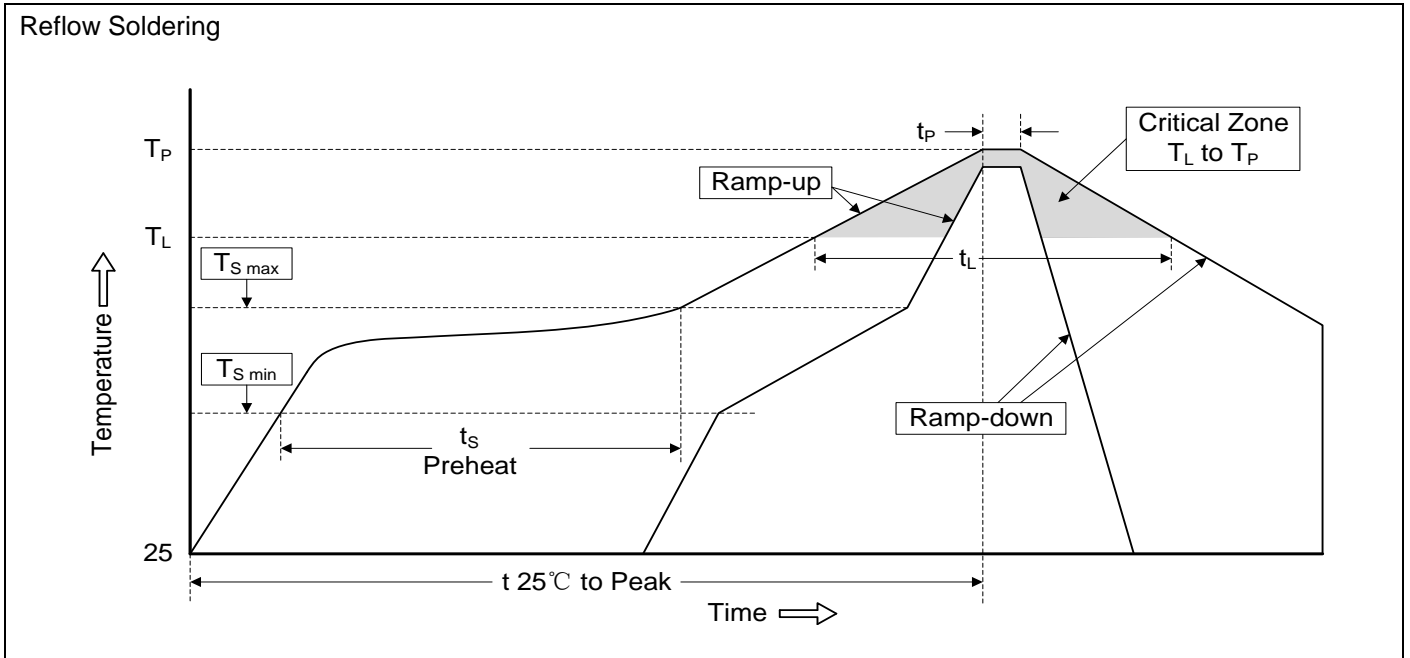


Figure 6. Maximum Non-Repetitive Forward Surge Current Uni-Directional Only



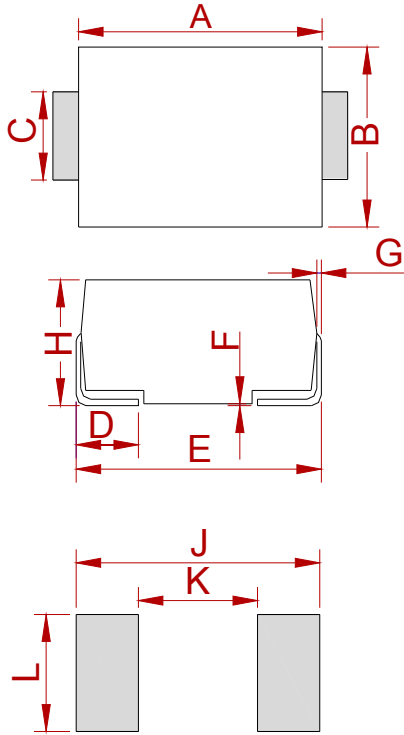
## Recommended Soldering Conditions



### Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate ( $T_L$ to $T_P$ )	3°C/second max.
Preheat	
-Temperature Min ( $T_{S \min}$ )	150°C
-Temperature Max ( $T_{S \max}$ )	200°C
-Time (min to max) ( $t_s$ )	60-180 seconds
$T_{S \max}$ to $T_L$	
-Ramp-up Rate	3°C/second max.
Time maintained above:	
-Temperature ( $T_L$ )	217°C
-Time ( $t_L$ )	60-150 seconds
Peak Temperature ( $T_P$ )	260°C
Time within 5°C of actual Peak Temperature ( $t_p$ )	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

**PACKAGE MECHANICAL DATA**



DO-214AA (SMB)

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.25	4.75	0.167	0.187
B	3.30	3.94	0.130	0.155
C	1.85	2.21	0.073	0.087
D	0.76	1.52	0.030	0.060
E	5.08	5.59	0.200	0.220
F	0.051	0.203	0.002	0.008
G	0.15	0.31	0.006	0.012
H	2.11	2.44	0.083	0.096
J	6.80		0.270	
K		2.60		0.100
L	2.40		0.090	

**REEL SPECIFICATION**

P/N	PKG	QTY
P6SMBXXXA(CA)(MS)	SMB	3000

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